

# SN74ALS2232A

## 64 × 8 ASYNCHRONOUS FIRST-IN, FIRST-OUT MEMORY

D3091, FEBRUARY 1988—REVISED MARCH 1990

- Independent Asynchronous Inputs and Outputs
- 64 Words by 8 Bits Each
- Data Rates From 0 to 40 MHz
- Fall-Through Time . . . 20 ns Typ
- 3-State Outputs

### description

This 512-bit memory uses Advanced Low-Power Schottky IMPACT-X™ technology and features high speed and fast fall-through times. It is organized as 64 words by 8 bits.

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. The function is used as a buffer to couple two buses operating at different clock rates. This FIFO is designed to process data at rates from 0 to 40 MHz in a bit-parallel format, word by word.

Data is written into memory on a low-to-high transition of the load clock input (LDCK) and is read out on a low-to-high transition of the unload clock input (UNCK). The memory is full when the number of words clocked in exceeds by 64 the number of words clocked out. When the memory is full, LDCK signals have no effect on the data residing in memory. When the memory is empty, UNCK signals have no effect.

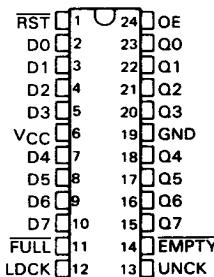
Status of the FIFO memory is monitored by the FULL and EMPTY output flags. The FULL output will be low when the memory is full, and high when the memory is not full. The EMPTY output will be low when the memory is empty, and high when it is not empty.

A low level on the reset input (RST) resets the internal stack control pointers and also sets EMPTY low and FULL high. The outputs are not reset to any specific logic levels. The first low-to-high transition on LDCK, either after a RST pulse or from an empty condition, causes EMPTY to go high and the data to appear on the Q outputs. The first word does not have to be unloaded. Data outputs are noninverting with respect to the data inputs and are at a high-impedance state when the output-enable input (OE) is low. The OE input does not effect either the FULL or EMPTY output flags. Cascading is easily accomplished in the word-width direction, but is not possible in the word-depth direction.

The SN74ALS2232A is characterized for operation from 0°C to 70°C.

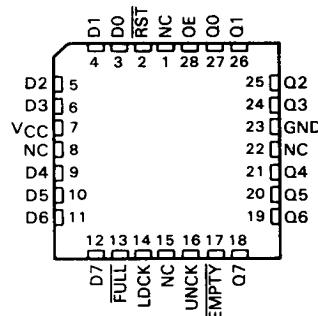
### NT PACKAGE

#### (TOP VIEW)



### FN PACKAGE

#### (TOP VIEW)



NC—No internal connection

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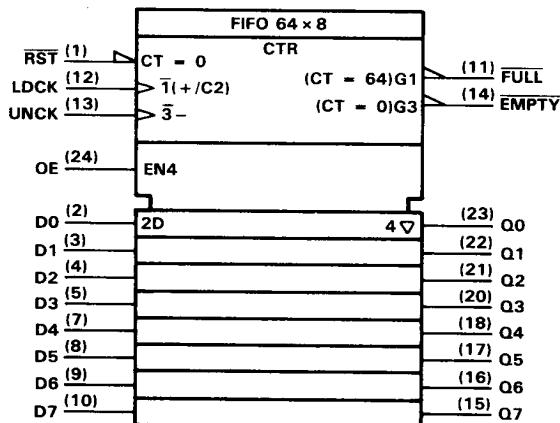
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logic symbol†



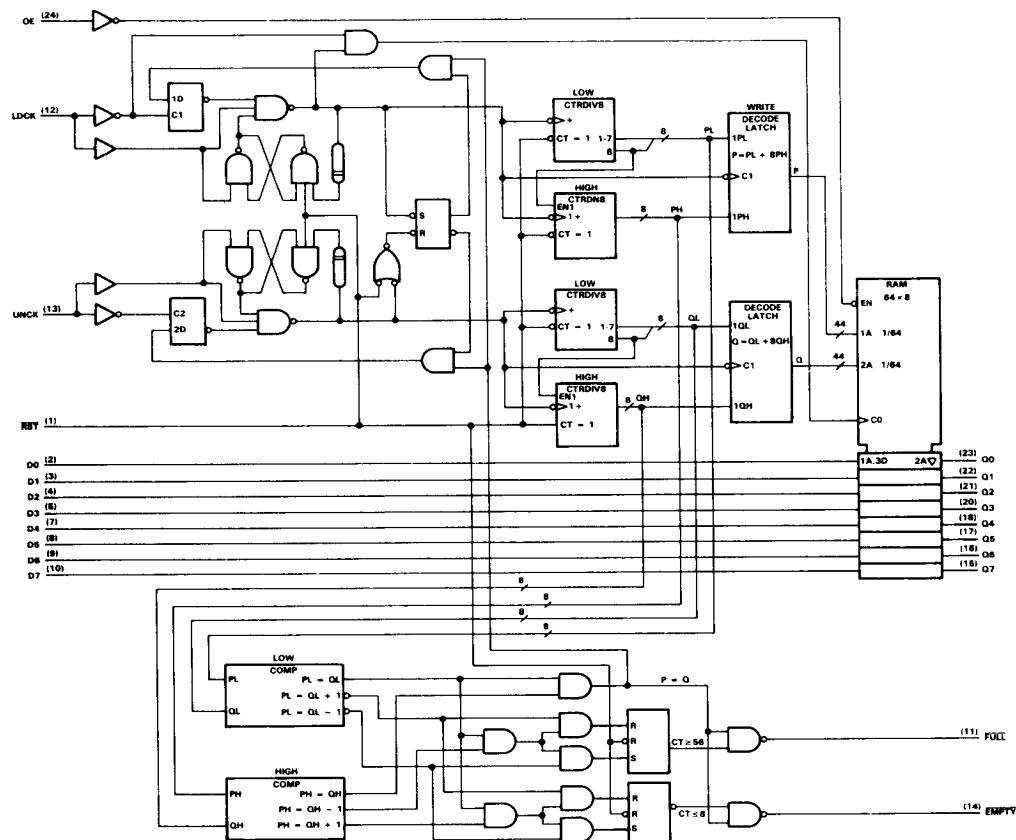
†This symbol is in accordance with ANSI/IEEE Standard 91-1984 and IEC Publication 617-12. The symbol is functionally accurate but does not show the details of implementation; for these, see the logic diagram. The symbol represents the memory as if it were controlled by a single counter whose content is the number of words stored at the time. Output data is invalid when the counter content (CT) is 0.

Pin numbers shown are for the NT package.

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## logic diagram (positive logic)

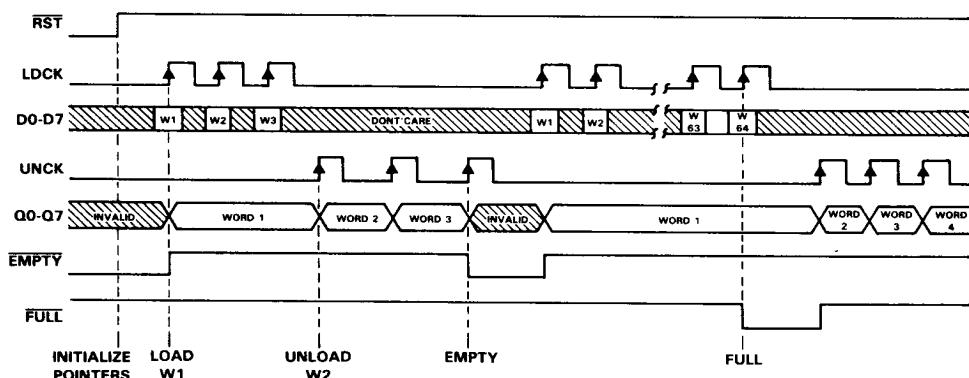


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**timing diagram**



**absolute maximum ratings over operating free-air temperature range**

Supply voltage, V <sub>CC</sub> .....	7 V
Input voltage .....	7 V
Voltage applied to a disabled 3-state output .....	5.5 V
Operating free-air temperature range .....	0°C to 70°C
Storage temperature range .....	-65°C to 150°C

**recommended operating conditions**

		MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage	4.5	5	5.5	V
V <sub>IH</sub>	High-level input voltage		2		V
V <sub>IL</sub>	Low-level input voltage			0.8	V
I <sub>OH</sub>	High-level output current			-2.6	mA
	Q outputs			-0.4	
	FULL, EMPTY				
I <sub>OL</sub>	Low-level output current			24	mA
	Q outputs			8	
	FULL, EMPTY				
f <sub>clock</sub>	Clock frequency	LDCK, UNCK	0	40	MHz
	RST low			25	
	LDCK low			13	
	LDCK high			12	
t <sub>w</sub>	Pulse duration	UNCK low		13	
		UNCK high		12	
t <sub>su1</sub>	Setup time, data before LDCK†		5		ns
t <sub>su2</sub>	Setup time, RST high (inactive) before LDCK†		5		ns
t <sub>h</sub>	Hold time, data after LDCK†		5		ns
T <sub>A</sub>	Operating free-air temperature		0	70	°C

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT	
VIK		V <sub>CC</sub> = 4.5 V, I <sub>I</sub> = -18 mA			1.2	V	
V <sub>OH</sub>	FULL, EMPTY	V <sub>CC</sub> = MIN TO MAX, I <sub>OH</sub> = 0.4 mA	V <sub>CC</sub> - 2			V	
	Q outputs	V <sub>CC</sub> = 4.5 V, I <sub>OH</sub> = -2.6 mA	2.4	3.2			
V <sub>OL</sub>	Q outputs	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 12 mA	0.25	0.4	V	
			I <sub>OL</sub> = 24 mA	0.35	0.5		
	FULL, EMPTY		I <sub>OL</sub> = 4 mA	0.25	0.4		
			I <sub>OL</sub> = 8 mA	0.35	0.5		
I <sub>OZH</sub>		V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 2.7 V			20	μA	
I <sub>OZL</sub>		V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 0.4 V			-20	μA	
I <sub>I</sub>		V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 7 V			0.1	mA	
I <sub>IH</sub>		V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 2.7 V			20	μA	
I <sub>IL</sub>	CLKS	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0.4 V			-0.2		
	Others				-0.1	mA	
I <sub>O</sub> <sup>‡</sup>	Q outputs	V <sub>CC</sub> = 5.5 V, FULL, EMPTY	V <sub>O</sub> = 2.25 V	-20	-130		
	FULL, EMPTY			-20	-112	mA	
I <sub>CC</sub>		V <sub>CC</sub> = 5.5 V		175	270	mA	

<sup>†</sup>All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.

<sup>‡</sup>The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I<sub>OS</sub>.

## switching characteristics (see Note 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 5 V, C <sub>L</sub> = 50 pF, R <sub>1</sub> = 500 Ω, R <sub>2</sub> = 500 Ω, T <sub>A</sub> = 25°C			V <sub>CC</sub> = 4.5 V to 5.5 V, C <sub>L</sub> = 50 pF, R <sub>1</sub> = 500 Ω, R <sub>2</sub> = 500 Ω, T <sub>A</sub> = 0°C to 70°C		UNIT
			MIN	TYP	MAX	MIN	MAX	
f <sub>max</sub>	LDCK				40			MHz
	UNCK				40			
t <sub>pd</sub>	LDCK <sup>†</sup>	Any Q	18	26			30	ns
t <sub>pd</sub>	UNCK <sup>†</sup>	Any Q	18	24			27	ns
t <sub>PLH</sub>	LDCK <sup>†</sup>	EMPTY	12	16			18	ns
t <sub>PLH</sub>	UNCK <sup>†</sup>	EMPTY	12	17			20	ns
t <sub>PHL</sub>	RST <sup>†</sup>	EMPTY	12	17			20	ns
t <sub>PHL</sub>	LDCK <sup>†</sup>	FULL	16	21			22	ns
t <sub>PLH</sub>	UNCK <sup>†</sup>	FULL	10	15			18	ns
t <sub>PLH</sub>	RST <sup>†</sup>	FULL	13	19			23	ns
t <sub>en</sub>	OE <sup>†</sup>	Q	11	15			17	ns
t <sub>dis</sub>	OE <sup>†</sup>	Q	11	17			19	ns

Note 1: Load circuit and voltage waveforms are shown in Section 1.

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